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METHOD AND APPARATUS FOR SUPPLEMENTARY COMMAND BUS

Field of Invention

The invention relates to integrated circuits and semiconductor systems, and more particularly, to accessing data.

Background of the Invention

Many electronic systems use memory to store information. Memory devices include an interface to communicate with other elements of the system. An ordinary interface provides several inputs and outputs, including various bus connections to accommodate multi-bit transfers in parallel. In particular, memory devices typically include a command bus and an address bus that transmit command and address information from a controller to the memory device.

For example, many existing DRAM devices include a command/address bus having three command signals, ordinarily row address strobe (RAS), column address strobe (CAS), and write enable (WE), and several address signals, including row/column address (A[X:0]), bank address (BA[1:0]), and chip select (CS). The command signals decode yielding several commands, such as ACTIVATE ROW, COLUMN SELECT with WRITE/READ, PRECHARGE ROW, PRECHARGE ALL, AUTO REFRESH, SELF REFRESH, WAKE, LOAD MODE, and LOAD EXTENDED MODE.

Certain access processes saturate the command/address bus, limiting the throughput/bandwidth of the memory device. For example, referring to Figure 9 illustrating a simplified memory access process, if the addressing patterns dictate all page misses, each burst transfer operation 900 of data to/from the memory devices requires one ACTIVATE command 910 for the row address 911 and one READ or WRITE command 912 corresponding to the column address data 913. Bank selection data is transferred via a bank selection bus 924. A PRECHARGE command 914 for the selected bank 915 is then asserted to close the selected bank. If the burst size does not allow time for three commands, however, the data transfer rate is throttled. A common example is a burst size of four data bus transfers 916A-D with the data bus 920 running at double the rate of the command/address bus 922. This is a simplified, illustrative example, for memory accesses typically utilize interleaved commands to the various banks to optimize the operation of the memory system, but it serves to illustrate that each data bus burst transfer operation 900

provides two command/address slots 910, 912. Because three commands are required to effect the transfer, however, the data bus efficiency may be reduced to two-thirds of its capacity.

Summary of the Invention

According to the present invention there is provided an electronic system, comprising:

a processor;

a memory having more than one memory location; and

a bus connecting the processor to the memory, wherein the bus comprises:

a main command bus configured to transfer an address-specific command, wherein said address-specific command is associated with a specific memory location; and

a supplementary command bus configured to transfer a general command, wherein said general command is a non-address-specific command.

The invention also provides a memory having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the general command is a non-address specific command.

The invention also provides a method of accessing a memory, comprising: in a first time slot, requesting activation of a first row; in a second time slot, requesting an access of a memory location in the first row; in a third time slot, requesting activation of a second row and requesting closure the first row.

The invention also provides a method of accessing a memory in an electronic system, comprising:

accessing a specific location in a memory, wherein the memory comprises more than one memory location, and wherein the specific memory location is accessed via a main command bus configured to transfer an address-specific command,

performing a general command, via a supplementary command bus, on the memory, wherein the general command is a non-address-specific command; and

wherein said accessing and performing steps occur over a bus that is configured to facilitate communication between a processor and the memory, and wherein the bus comprises: the main command bus and the supplementary command bus.

The invention also provides an electronic system, comprising:

a processor; a memory having more than one memory location; and

a bus connecting the processor to the memory, wherein

the bus comprises:

a data bus for transmitting data; an address bus for identifying a first memory location; a main command bus for transferring a first command that relates to the first memory location; and

a supplementary command bus for transferring a second command, wherein the second command does not relate to the first memory location.

The invention also provides an electronic system, comprising:

a processor;

a memory having more than one memory location; and

a bus connecting the processor to the memory, wherein

the bus comprises: a main command bus configured to transfer an address-specific command; and

a supplementary command bus configured to transfer a general command.

The invention also provides a memory system, comprising:

a memory controller; and

a memory in communication with the memory controller,

wherein the memory includes an interface, comprising:

a main control interface for receiving a location-specific command; and

a supplementary control interface for receiving a general command.

The invention also provides a method for accessing a memory comprising the steps of:

asserting a first signal on a supplementary chip select bus,

wherein assertion of the first signal on the supplementary chip select bus executes a supplementary command on a first memory bank, wherein the first memory bank is designated by the first signal on the supplementary chip select bus and a second signal on a supplementary bank select bus; and

asserting, via a main command bus, a main command on the first memory bank.

The invention also provides a method for accessing a memory comprising the steps of:

asserting a signal on a supplementary command bus, wherein assertion of the signal on the supplementary command bus executes a supplementary command on a first memory bank; and

asserting, via a main command bus, a main command on the first memory bank.

The invention also provides a method for accessing a memory comprising the steps of:

activating rows and select columns for memory access operations using a main control bus; and

closing banks of memory using a supplementary control bus.

The invention also provides a method for accessing a memory comprising the steps of:

asserting a first signal on a supplementary command bus,

wherein assertion of the first signal on the supplementary command bus executes a supplementary command on a first memory bank, wherein the step of asserting the first signal on the supplementary command bus further comprises packetizing of the supplementary command;

and asserting, via a main command bus, a main command on the first memory bank.

The invention also provides a memory device having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the memory device is a DDR memory device.

The invention also provides a memory device having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the memory device is a SDRAM memory device.

The invention also provides a memory device comprising:

an interface that is configured to communicate with a supplementary control bus, wherein the supplementary control bus comprises: a supplementary command bus, a supplementary chip select bus, and a supplementary bank select bus;

wherein the supplementary command bus is a one-bit bus that is configured to

communicate a supplementary command bit, and wherein assertion of the supplementary command bit causes execution of a PRECHARGE command on a first memory bank that is identified by signals from the supplementary chip select bus and the supplementary bank select bus.

The invention also provides a memory comprising:

an interface that is configured to communicate with a supplementary control bus, wherein the supplementary control bus comprises: a supplementary chip select bus, and a supplementary bank select bus;

wherein activation of the supplementary chip select bus causes execution of a PRECHARGE command on a first memory bank that is identified by signals on the supplementary chip select bus and the supplementary bank select bus.

An electronic system according to various embodiments of the present invention includes a memory having a location-specific command interface and a general command interface. The memory may communicate with other components in the system via a main command bus configured to transfer address-specific commands and a supplementary command bus configured to transfer general commands. Commands may be received by the memory simultaneously at the respective interfaces. For example, a PRECHARGE command may be received on the general command interface while a memory access is received on the location-specific interface.

Brief Description of the Drawings

A more complete understanding of the present invention may be derived by referring to the detailed description and claims when considered in connection with the following illustrative Figures, which may not be to scale. In the following Figures, like reference numbers refer to similar elements throughout the Figures.

Figure 1 is a block diagram of an electronic system according to various aspects of the present invention;

Figure 2 is a block diagram of a memory interface and a bus system;

Figure 3 is a block diagram of a main control bus and a supplementary control bus;

Figure 4 is a timing diagram for consecutive memory accesses;

Figure 5 is a block diagram of an alternative embodiment of a main control bus and

a supplementary control bus;

Figure 6 is another alternative embodiment of a main control bus and a supplementary control bus;

Figure 7 is a timing diagram for providing a secondary command indicator;

Figure 8 is a timing diagram for providing a tertiary command indicator; and

Figure 9 is a timing diagram for a simplified, illustrative prior art memory access.

Elements in the figures are illustrated for simplicity and clarity and have not necessarily been drawn to scale. For example, the dimensions of some of the elements in the

figures may be exaggerated relative to other elements to help to improve understanding of embodiments of the present invention.

Detailed Description

The present invention may be described in terms of functional block components and various processing steps. Such functional blocks may be realized by any number of hardware and software components configured to perform specified functions. For example, the present invention may employ various components, e.g., memory elements, interface elements, logic elements, buses, package connections, and the like, which may carry out a variety of functions under the control of one or more processors or other control devices. In addition, the present invention may be practiced in conjunction with any number of storage systems and data transmission media and protocols and the systems described are merely exemplary applications of the invention. Further, the present invention may employ any number of conventional techniques for data transmission, signaling, data processing, bus control, and the like.

Referring to Figure 1, an electronic system 100 according to various aspects of the present invention may include a processor 102 and a memory system 104. The present electronic system 100 comprises a system using a memory, such as a personal computer system. The electronic system 100 may comprise, however, any suitable electronic system, such as a communication system, computing system, entertainment system, control system, portable electronic device, audio component, appliance, or factory control system, and the various components may differ according to the particular system and environment. The processor 102 generally controls operation of the electronic system 100, and may comprise any appropriate processor or controller, such as an Intel, Motorola, or Advanced Micro Devices microprocessor. In some applications, the processor 102 may be replaced by other devices, such as logic circuits or ASICs, or omitted altogether.

The memory system 104 comprises a storage system for storing data. The memory system 104 may comprise any appropriate memory system for storing data and transferring data between the memory system 104 and the processor 102 or another component. In the present embodiment, the memory system 104 includes one or more memory modules 210A, B, a memory controller 212, and a bus system 106. The memory controller 212 controls access to, including data transfers to and from, the memory modules 210, and may perform further functions and operations as well. The memory controller 212 may comprise any

suitable memory controller for controlling access to the memory modules 210. In some embodiments, the memory controller 212 may be omitted and/or have its functions performed by other system components.

The memory modules 210 may comprise any system for storing data, such as a ROM, SRAM, DRAM, SDRAM, or any other suitable storage system. In the present embodiment, the memory modules 210 comprise double data rate synchronous dynamic random access memory (DDR SDRAM) modules from Micron. For example, each memory module 210 suitably comprises a high-speed CMOS SDRAM internally configured as four banks of DRAMs. The memory modules 210, however, may comprise any appropriate memory or configuration, such as an individual memory chip, a multi-component device, or another type of storage device altogether. The memory modules 210 interface with the rest of the electronic system 100 through any suitable interface, such as a plurality of connections comprising pins, solder, conductive connections, optical couplings, or any other suitable coupling.

The bus system 106 connects the components of the memory system 104. The memory system 104, including the bus system 106, may utilize any appropriate signals, including optical or electric signals. The bus system 106 may comprise any suitable medium for transferring information, such as a plurality of wires, optical fibers, or other communication medium. In the present embodiment, the medium comprises an electronic bus, such as a serial bus or multi-bit bus, to which the memory system 104 and other components may be attached.

Communications with the memory system 104 may be controlled in any suitable manner and by any suitable component, such as using the processor 102, the memory controller 212, or other circuit or system to control communications. In the present embodiment, communications with the memory module 210 are suitably controlled by the memory controller 212.

The bus 106 and the connected components may communicate using any appropriate communication techniques and/or protocols. For example, the components may communicate via the bus 106 using a selected conventional protocol, such as those described in specifications for Micron SDRAMs. The bus 106 is also suitably configured to communicate with the memory modules 210. For example, referring to Figure 2, each memory module 210 includes an interface 250 having a data bus connection 320, address bus connection 324, main command bus connection 326, and supplementary command bus

connection 328. The bus 106 may be configured accordingly to facilitate communication, such as including a data bus 220, an address bus 224, a main control bus 226, and a supplementary control bus 228.

The memory interface 250 and the bus 106 provide one or media for transferring information to and from the memory module 210. Each bus component 220, 224, 226, 228 ordinarily transfers a selected type of information, i.e., address selection information on the address bus 224, data on the data bus 220, and command signals on the main control bus 226 and the supplementary control bus 228. Further, each bus may be suitably configured to transfer the relevant information. For example, each bus may be configured to handle a selected number of bits.

More particularly, the data bus interface 320 of the present embodiment comprises a multibit, such as 4-, 8-, or 16-bit, connection for transferring information to and from the data bus 220. The address bus interface 324 of the present embodiment comprises a 13-bit connection for, among other things, receiving row and column address information to select one location out of the memory array 210 in a selected bank. The data bus 220 and address bus 224 are suitably configured to interface with the memory module 210 via the corresponding interfaces 320, 324.

Signals on the main control bus 226 and the supplementary control bus 228 define commands, and may further identify the chips and/or banks to which the commands apply. The commands may be any set of commands for operation of the memory module 210. In the present embodiment, the supplementary control bus 228 is used to provide a first selected subset of commands and the main control bus 226 to provide a second selected subset or, alternatively, the entire set of commands. For example, the supplementary control bus 228 may be used for general commands, i.e., commands that relate to large blocks of memory locations (like the entire module or an entire bank). The main control bus 226 handles location-specific commands, i.e., that relate to specific individual locations or groups of locations in the memory module 210, as well as other commands in various embodiments. The memory location relating to the location-specific command may be indicated in any suitable manner, such as by signals on the address bus 224. Thus, the main control bus 226 is used for commands using row and/or column information, typically provided via the address bus 224, and the supplementary control bus 228 is used for commands that are not associated with row or column information, and thus do not utilize the address bus 224.

Command signals may be divided between the main control bus 226 and the supplementary control bus 228 in any suitable manner; similarly, the main control bus 226 and the supplementary control bus 228 may be configured in any suitable manner to accommodate the command signals. For example, in one embodiment illustrated in Figure 3, the main control bus 226 comprises a main command bus 410 having three main command bits (M-CMD), a main chip select bus bit 412 having one bit (M-CS), and a main bank selection bus 414 having two bits (M-BA). The three main command bits are suitably designated as a row address strobe (RAS), a column address strobe (CAS), and a write enable (WE). In the present embodiment, the main bank selection bus 222 comprises a two-bit bus which defines the bank to which a command is to be applied, and the one-bit main chip select bus 412 identifies the relevant chip for the corresponding operation.

Similarly, the supplementary control bus 228 may be configured in any suitable manner to accommodate the relevant command set. For example, the supplementary control bus 228 suitably comprises a supplementary command bus 416 (S-CMD), a supplementary chip select bus 418 (S-CS), and a supplementary bank selection bus 420 (S-BA). In one embodiment, the supplementary control bus 228 solely facilitates PRECHARGE operations. PRECHARGE operations may comprise operations to deactivate open rows in a particular bank or all banks of the memory, though the PRECHARGE operation may comprise any appropriate process for preparing a memory or portion of memory for access or restoring a memory to a selected state following an access.

In the present dedicated PRECHARGE embodiment, the supplementary command bus 416 is a one-bit signal such that assertion of the supplementary command bit signals the memory module 210 to execute a PRECHARGE command on the bank 310A indicated by the supplementary chip select bus 418 and supplementary bank selection bus 420. Alternatively, because PRECHARGE is the only command controlled by the supplementary control bus 228, the supplementary command bus 416 may be omitted altogether, so that the supplementary chip select bus operates as the PRECHARGE signal. Activation of the supplementary chip select causes a PRECHARGE operation on the indicated chip in the bank designated by the supplementary bank selection bus 420.

Thus, the ACTIVE and subsequent READ or WRITE commands may be asserted using the main control bus 226 in conjunction with the address bus 224 to retrieve or store data. The next ACTIVE command or other command may then be asserted via the main control bus 226 on another bank 310B concurrently with assertion of a PRECHARGE

command on the original bank 310A via the supplementary control bus 228. Accordingly, the PRECHARGE commands may be asserted without using the main control bus 226, thus relieving congestion on the main control bus 226 and tending to improve the performance of the memory module 210.

More particularly, an electronic system 100 and method according to various aspects of the present invention may use the main control bus 226 to activate rows and select columns for memory access operations and the supplementary control bus 228 to close banks of memory. For example, referring to Figure 4, an initial memory access may be performed by identifying the relevant bank on the main bank selection bus 414, the relevant chip on the main chip select bus 412, and the relevant memory row on the address bus 224, and providing the ACTIVE signal on the main command bus 410 at a first time T1. At substantially the same time, the supplementary control bus 228 receives a NOP command to prevent any unwanted command from being registered on the supplementary control bus 228.

Following the initial memory access, a second memory access operation may be initiated at a second memory location on a different bank. Accordingly, the second memory location may be identified on the main chip select bus 412, main bank select bus 414, and address bus 224, and the ACTIVE and READ or WRITE commands may be successively provided via the main command bus 410 at times T3 and T4. Meanwhile, the supplementary control bus 228 may provide a PRECHARGE command to a previously accessed bank to close the still-active row from the preceding memory access operation. For example, the previously accessed bank and chip are identified on the supplementary bank selection bus 420 and supplementary chip select bus 418, respectively, at time T3. The PRECHARGE command is provided on the supplementary command bus 416 to initiate the precharge of the previously accessed bank while the second bank is being accessed via the main control bus 226.

The command set may be apportioned and/or shared by the main control bus 226 and the supplementary control bus 228 in any suitable manner. For example, the commands may be shared such that all of the commands requiring the address bus 224 are asserted via the main control bus 226, and all of the commands that do not require the address bus 224 may be asserted via either the supplementary control bus 228 or the main control bus 226. Thus, the device providing the commands, such as the memory controller 212, may select which control bus 226, 228 on which to provide a command according to any selected criteria.

Alternatively, the commands may be restricted to assertion on either the main control bus 226 or the supplementary control bus 228, or the commands may be apportioned such that one set of commands is asserted only on the main control bus 226, a second set is asserted only on the supplementary control bus 228, while a third set may be asserted on either bus 226, 228.

Similarly, memory module interface 250, the main control bus 226, and the supplementary control bus 228 may be configured in any suitable manner to facilitate assertion of the commands as apportioned or shared. In the embodiment in which all commands not requiring the address bus 224 may be asserted on either the main control bus 226 or the supplementary control bus 228, the respective control buses 226, 228 are suitably configured with sufficient bits to accommodate the relevant command set. For example, referring to Figure 5, the memory module 210 may accommodate nine commands such that three commands require the address bus 224 (such as ACTIVE, READ, and WRITE) and six commands do not (such as DESELECT, NO OPERATION, BURST TERMINATE, PRECHARGE, AUTO REFRESH, and LOAD MODE REGISTER). To accommodate all nine commands, the main control bus 226 may be configured with four command bits. Similarly, the supplementary control bus 228 is suitably configured with three command bits to accommodate the six commands that do not use the address bus 224.

In alternative embodiments, the number of pins may be reduced by reconfiguring the command set and the main and supplementary command buses 226, 228 and the interface 250. For example, the commands may be apportioned such that commands not requiring the address bus 224 are asserted only on the supplementary control bus 228. Thus, in the present embodiment, the main control bus 226 may be configured to handle only three commands (ACTIVE, READ, and WRITE), requiring only two command bits, as illustrated in Figure 6.

In another embodiment, the number of bits required by the supplementary control bus 228 may be reduced by packetizing various commands. Packetizing comprises sending consecutive signals for a single command, such as for lower priority commands. For example, referring to Figure 7, the supplementary control bus 228 may be configured with two supplementary command bits 416 as well as the supplementary chip select 418 and supplementary bank select bits 420. The supplementary command bits 416 may receive one of four main commands. Three commands are suitably executable commands, such as PRECHARGE, AUTO REFRESH, and NOP. The fourth command may be a secondary

command indicator 620, referred to in this embodiment as EXTEND1. EXTEND1 designates a secondary command 622 following, for example, in the next cycle. Thus, if EXTEND1 is transmitted, the next cycle contains the secondary command 622. The secondary commands may comprise any appropriate commands, such as SELF REFRESH, WAKE, or LOAD MODE. In the present embodiment, the secondary commands comprise commands that are lower priority than the main commands. The main and secondary command sets may be selected, however, according to any desired criteria.

Further, referring to Figure 8, the secondary command 622 may indicate another command following, such as in the next cycle, by asserting a tertiary command indicator 724 (EXTEND2). The tertiary command 726 may then be asserted in the following cycle. Additional command capability may be provided using additional sub-command indicators if desired. Thus, many low priority commands may be added without adding additional command bits.

It should be appreciated that the particular implementations shown and described herein are illustrative of the invention and its best mode and are not intended to otherwise limit the scope of the present invention in any way. Indeed, for the sake of brevity, conventional signal processing, data transmission, and other functional aspects of the systems (and components of the individual operating components of the systems) may not be described in detail herein. Furthermore, the connecting lines shown in the various figures contained herein are intended to represent exemplary functional relationships and/or physical couplings between the various elements. It should be noted that many alternative or additional functional relationships or physical connections may be present in a practical communication system.

The present invention has been described above with reference to a preferred embodiment. However, those skilled in the art having read this disclosure will recognize that changes and modifications may be made to the preferred embodiment without departing from the scope of the present invention. These and other changes or modifications are intended to be included within the scope of the present invention, as expressed in the following claims.

Claims

1. An electronic system (100), comprising:

a processor (102);

a memory (104) having more than one memory location (210A, 210B); and

a bus (106) connecting the processor to the memory, wherein the bus comprises:

a main command bus (226) configured to transfer an address-specific command, wherein said address-specific command is associated with a specific memory location; and

a supplementary command bus (228) configured to transfer a general command, wherein said general command is a non-address-specific command.

2. An electronic system according to claim 1, wherein the bus comprises a data bus (220) for transmitting data.

3. An electronic system according to claim 1 or claim 2, wherein the bus comprises an address bus (224) for identifying a first memory location for the address-specific command.

4. An electronic system according to claim 3, wherein the general command does not relate to the first memory location.

5. An electronic system according to claim 1, wherein the general command is a PRECHARGE command.

6. An electronic system according to claim 5, wherein the supplementary command bus (228) comprises a one-bit bus.

7. An electronic system according to claim 1, wherein: the main command bus (226) transfers location-specific commands; and the supplementary command bus (228)

transfers only general commands, and wherein said general command is a command that is associated with more than one memory locations.

8. An electronic system according to claim 1, wherein: the general command is a secondary command indicator; and the supplementary command bus (228) transfers a third command after the general command.

9. A memory having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the general command is a non-address specific command.

10. A memory according to claim 9, wherein the interface further comprises: a location-specific command interface configured to receive location-specific commands.

11. A memory according to claim 9 or claim 10, wherein the general command interface is configured to receive a PRECHARGE command.

12. A memory according to claim 10, wherein the location-specific command interface is configured to receive location-specific commands and general commands.

13. A memory according to claim 9, wherein the memory includes more than one bank, and the interface further comprises a general bank select interface configured to receive bank address information for the general command.

14. A memory according to claim 9, further comprising a one-bit PRECHARGE input dedicated to receiving a PRECHARGE command, and wherein the general command is a command that is associated with a bank of memory locations.

15. A memory according to claim 14, wherein the memory includes more than one bank, further including a general bank select interface configured to receive bank address information for the PRECHARGE command.

16. A memory system (104), comprising: a memory controller (212); and a memory according to claim 9 in communication with the memory controller, wherein the general command interface is a supplementary control interface for receiving the general command, and wherein the memory interface further comprises: a main control interface for receiving a location-specific command.

17. A memory system (104) according to claim 16, wherein the general command is a PRECHARGE command.

18. A memory system (104) according to claim 16, wherein: the general command is a secondary command indicator; and the supplementary control interface is configured to transfer a secondary command after the secondary command indicator.

19. An electronic system (100), comprising:

a processor (102); and

a memory system (104) connected to the processor, the memory system comprising:

a memory controller (212) connected to the processor; and

a memory, according to claim 9, connected to the memory controller (212), wherein the memory interface further comprises:

an address interface for receiving an address signal;

a main control interface, comprising:

a main command bus for receiving a first command signal relating to a memory location specified by the address signal; and a main bank select bus for receiving a first bank select signal specifying a first bank corresponding to the first command signal; and

wherein the general command interface comprises:

a supplementary command bus for receiving a second command signal, corresponding to the general command; and a supplementary bank select bus for receiving a second bank select signal specifying a

second bank corresponding to the second command signal.

20. An electronic system according to claim 19, wherein the general command is a PRECHARGE command and wherein the general command interface is configured to receive a PRECHARGE command.

21. An electronic system according to claim 19, wherein the supplementary command bus comprises a one-bit bus.

22. An electronic system according to claim 19, wherein the main control interface is configured to receive location-specific commands and general commands.

23. An electronic system according to claim 19, wherein the general command interface further comprises a one-bit PRECHARGE input dedicated to receiving a PRECHARGE command.

24. A method of accessing a memory, comprising: in a first time slot, requesting activation of a first row; in a second time slot, requesting an access of a memory location in the first row; in a third time slot, requesting activation of a second row and requesting closure the first row.

25. A method according to claim 24, further comprising: providing a main command bus (226), wherein the requesting activation of the second row occurs on the main command bus; and providing a supplementary command bus (228), wherein the requesting closure of the first row occurs on the supplementary command bus.

26. A method of accessing a memory in an electronic system (100), comprising:

accessing a specific location in a memory (104), wherein the memory comprises more than one memory location (210A, 210B), and wherein the specific memory location is accessed via a main command bus (226) configured to transfer an address-specific command,

performing a general command, via a supplementary command bus (228), on the memory, wherein the general command is a non-address-specific command; and

wherein said accessing and performing steps occur over a bus (106) that is configured to facilitate communication between a processor (102) and the memory, and wherein the bus comprises: the main command bus (226) and the supplementary command bus (228).

27. The method of claim 26 wherein the accessing step further comprises sending a memory address signal over a data bus (220).

28. The method of claim 26 wherein a specific address of said memory is accessed during the same cycle as a separate general command is performed on a block of memory elsewhere on the memory.

29. The method of claim 26 wherein the general command is a PRECHARGE command.

30. The method of claim 26 wherein the supplementary command bus (228) comprises a one-bit bus.

31. The method of claim 26 wherein the main command bus (226) transfers location-specific commands, wherein the supplementary command bus (228) transfers only general commands, and wherein said general command is a command that is associated with more than one memory locations.

32. The method of claim 26 wherein the accessing step further comprises the step of activating, during a first cycle, a first specific memory location, and wherein the accessing step further comprises the step of activating, during a second cycle, a second specific memory location that is located in a different bank of the memory from the first specific memory location, and wherein said performing step further comprises the step of closing, during the second cycle, a bank of memory locations comprising the first specific memory location.

33. An electronic system, comprising:

a processor; a memory having more than one memory location; and

a bus connecting the processor to the memory, wherein

the bus comprises:

a data bus for transmitting data; an address bus for identifying a first memory location; a main command bus for transferring a first command that relates to the first memory location; and

a supplementary command bus for transferring a second command, wherein the second command does not relate to the first memory location.

34. An electronic system, comprising:

a processor;

a memory having more than one memory location; and

a bus connecting the processor to the memory, wherein

the bus comprises: a main command bus configured to transfer an address-specific command; and

a supplementary command bus configured to transfer a general command.

35. A memory system, comprising:

a memory controller; and

a memory in communication with the memory controller,

wherein the memory includes an interface, comprising:

a main control interface for receiving a location-specific command; and

a supplementary control interface for receiving a general command.

36. A method for accessing a memory comprising the steps of:

asserting a first signal on a supplementary chip select bus,

wherein assertion of the first signal on the supplementary chip select bus executes a supplementary command on a first memory bank, wherein the first memory bank is designated by the first signal on the supplementary chip select bus and a second signal on a supplementary bank select bus; and

asserting, via a main command bus, a main command on the first memory bank.

37. A method for accessing a memory comprising the steps of:

asserting a signal on a supplementary command bus, wherein assertion of the signal on the supplementary command bus executes a supplementary command on a first memory bank; and

asserting, via a main command bus, a main command on the first memory bank.

38. A method for accessing a memory comprising the steps of:

activating rows and select columns for memory access operations using a main control bus; and

closing banks of memory using a supplementary control bus.

39. A method for accessing a memory comprising the steps of:

asserting a first signal on a supplementary command bus,

wherein assertion of the first signal on the supplementary command bus executes a supplementary command on a first memory bank, wherein the step of asserting the first signal on the supplementary command bus further comprises packetizing of the supplementary command;

and asserting, via a main command bus, a main command on the first memory bank.

40. A memory device having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the memory device is a DDR memory device.

41. A memory device having an interface, wherein the interface comprises a general command interface configured to receive a general command, and wherein the memory device is a SDRAM memory device.

42. A memory device comprising:

an interface that is configured to communicate with a supplementary control bus, wherein the supplementary control bus comprises: a supplementary command bus, a supplementary chip select bus, and a supplementary bank select bus;

wherein the supplementary command bus is a one-bit bus that is configured to communicate a supplementary command bit, and wherein assertion of the supplementary command bit causes execution of a PRECHARGE command on a first memory bank that is identified by signals from the supplementary chip select bus and the supplementary bank select bus.

43. A memory comprising:

an interface that is configured to communicate with a supplementary control bus, wherein the supplementary control bus comprises: a supplementary chip select bus, and a supplementary bank select bus;

wherein activation of the supplementary chip select bus causes execution of a PRECHARGE command on a first memory bank that is identified by signals on the supplementary chip select bus and the supplementary bank select bus.